## TOSHIBA SUPER FAST RECOVERY RECTIFIER SILICON DIFFUSED TYPE

# 3 G U 4 1

#### SWITCHING TYPE POWER SUPPLY APPLICATIONS

Repetitive Peak Reverse Voltage  $: V_{RRM} = 100 \sim 400 V$ 

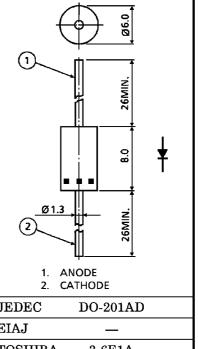
Average Forward Current  $: I_{F(AV)} = 3.0A$ 

Very Fast Reverse-Recovery Time : trr=100ns

#### **MAXIMUM RATINGS**

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Reverse Voltage	$v_{RRM}$	400	V	
Average Forward Current	I <sub>F (AV)</sub>	3.0	Α	
Peak One Cycle Surge Forward	Trong	80 (50Hz)	A	
Current (Non-Repetitive)	IFSM	88 (60Hz)		
Junction Temperature	$T_j$	-40~150	$^{\circ}\mathrm{C}$	
Storage Temperature Range	$\mathrm{T_{stg}}$	-40~150	°C	

Unit in mm



**JEDEC EIAJ** 3-6E1A **TOSHIBA** 

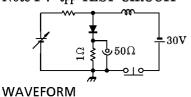
Weight: 1.18g

### ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	${ m V_{FM}}$	$I_{\text{FM}} = 3.0 \text{A}$	_	_	1.5	V
Repetitive Peak Reverse Current	$I_{RRM}$	$V_{RRM} = 400V$	_	_	300	$\mu$ A
Reverse Recovery Time (Note 1)	$ m t_{rr}$	$I_F=1A$ , $di/dt=-30A/\mu s$	_	_	100	ns
Forward Recovery Time (Note 2)	$t_{fr}$	$I_{\mathrm{F}} = 1.0 \mathrm{A}$	_	_	200	ns
Thermal Resistance (Note 3)	$ m R_{th~(j-a)}$	Junction to Ambient	_	_	37	°C/W
Thermal Resistance (Note 4)	$\mathrm{R}_{\mathrm{th}(j-\ell)}$	Junction to Lead	_	_	12	°C/W

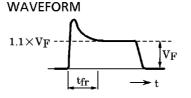
Note 1: trr TEST CIRCUIT

 $I_F = 1.0A$ 



 $di/dt = -30A/\mu s$ 

10%· I<u>RP</u>

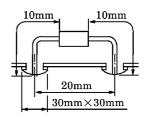


Note  $2: t_{fr}$  TEST CIRCUIT

 $30\Omega$ 

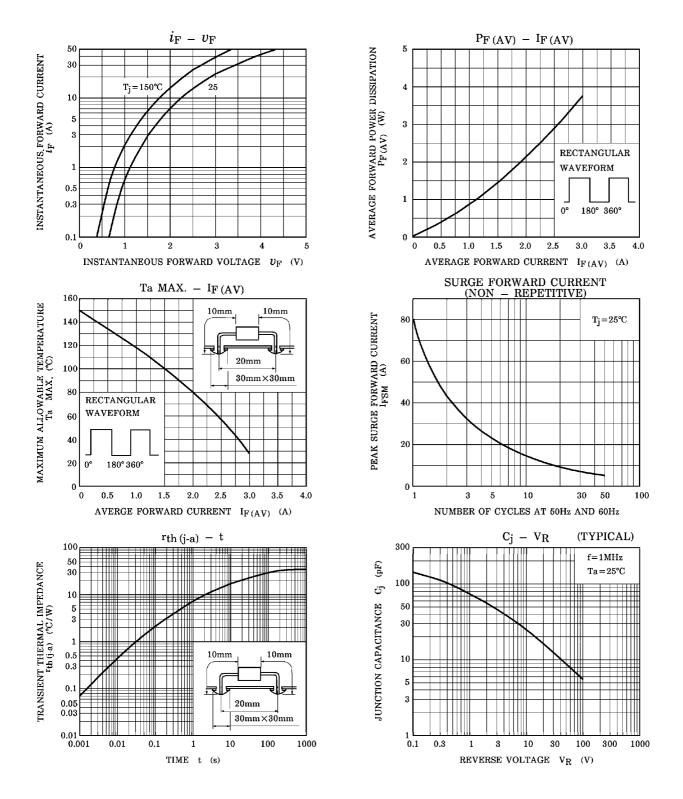
○ OUTPUT

Note 3: THERMAL RESISTANCE



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